NSN 5962-01-260-8676

Memory Microcircuit - Page 1 of 2



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Body Length: 1.375 inches Body Widh: 0.500 inches Body Height: 0.185 inches Maximum Power Dissipation Rating: 1.0 watts Operating Tempurature Range: -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius Fortures Provided: Monoithic and static operation Inclosure Material: Metal or plaster or ceramic Inclosure Configuration: Dual-Inline Output Logic Form: Complementary-metal exide-semiconductor logic Input Circuit Pattern: 21 Input Complementary-metal exide-semiconductor logic Interminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source Memory Device Type: Ram Solder Solder Solder Solder Solder Solder Solder Solder Solder Solder <th></th> <th></th>		
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